NSN 5961-01-321-1916

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-321-1916 **Inclosure Material:** Metal **Overall Length:** Between 1.067 inches and 1.168 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-4 **Mounting Method:** Threaded stud **Overall Width Across Flats:** Between 0.423 inches and 0.437 inches **Thread Size:** 0.190 inches **Criticality Code Justification:** Zzzy **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 300.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes source cutoff current preset and 120.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** Item must comply with requirements of defense supply center columbus production standard no. Lo4258 **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Reference Number Differentiating Characteristics:** Breference number differentiating material will be in accordance with naval inventory control point activity hx quality control. Manufacturing and testing specifications available at the dla icp. Shelf Life: N/a **Unit Of Measure: Demilitarization:**